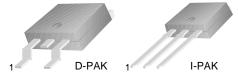


## **MJD340**

### **High Voltage Power Transistors D-PAK for Surface Mount Applications**

- Lead Formed for Surface Mount Applications (No Suffix)
  Straight Lead (I-PAK, "- I" Suffix)



1.Base 2.Collector 3.Emitter

## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	300	V
$V_{CEO}$	Collector-Emitter Voltage	300	V
V <sub>EBO</sub>	Emitter-Base Voltage	3	V
I <sub>C</sub>	Collector Current (DC)	0.5	Α
I <sub>CP</sub>	Collector Current (Pulse)	0.75	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	15	W
	Collector Dissipation (T <sub>a</sub> =25°C)	1.56	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector Emitter Sustaining Voltage	$I_{C} = 1 \text{mA}, I_{B} = 0$	300		V
I <sub>CEO</sub>	Collector Cut-off Current	$V_{CB} = 300V, I_{E} = 0$		0.1	mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 3V, I_{C} = 0$		0.1	mA
h <sub>FE</sub>	* DC Current Gain	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA	30	240	

<sup>\*</sup> Pulse Test: PW≤300μs, Duty Cycle≤2%

# **Typical Characteristics**

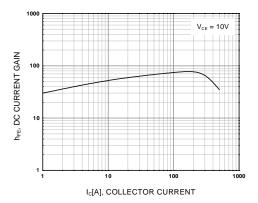


Figure 1. DC current Gain

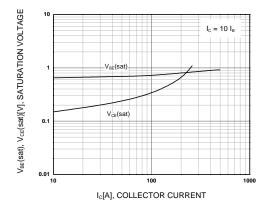


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

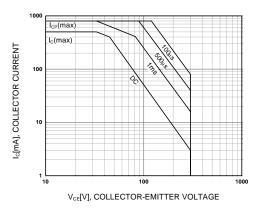


Figure 3. Safe Operating Area

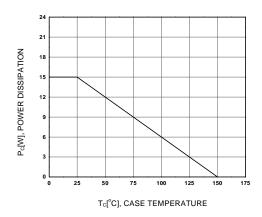
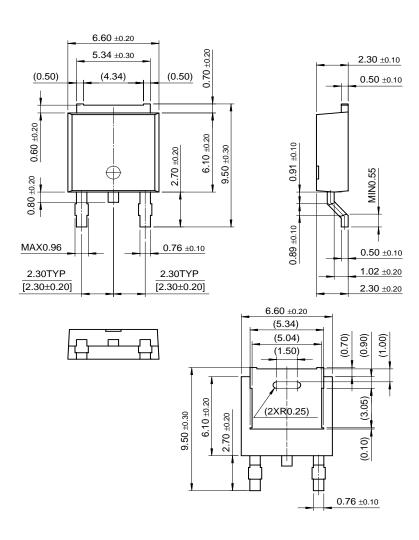


Figure 4. Power Derating

# **Package Demensions**

# D-PAK



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